



Integrated Device Technology, Inc.

HIGH-SPEED 4K x 8 DUAL-PORT STATIC RAM WITH SEMAPHORE

IDT71342SA/LA

FEATURES:

- High-speed access
 - Commercial: 20/25/35/45/55/70ns (max.)
- Low-power operation
 - IDT71342SA
 - Active: 500mW (typ.)
 - Standby: 5mW (typ.)
 - IDT71342LA
 - Active: 500mW (typ.)
 - Standby: 1mW (typ.)
- Fully asynchronous operation from either port
- Full on-chip hardware support of semaphore signalling between ports
- Battery backup operation—2V data retention
- TTL-compatible; single 5V ($\pm 10\%$) power supply
- Available in plastic packages
- Industrial temperature range (-40°C to $+85^{\circ}\text{C}$) is available, tested to military electrical specifications

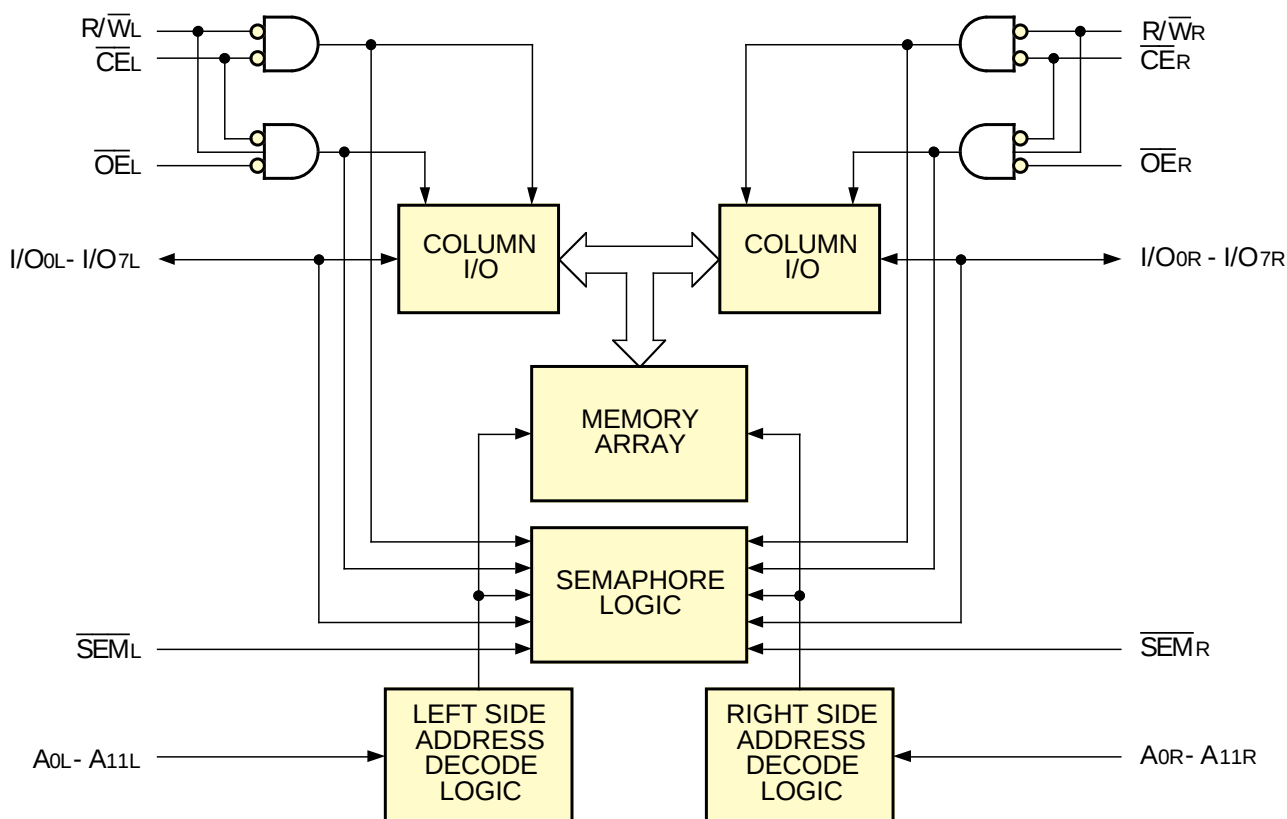
DESCRIPTION:

The IDT71342 is an extremely high-speed 4K x 8 Dual-Port Static RAM with full on-chip hardware support of semaphore signalling between the two ports.

The IDT71342 provides two independent ports with separate control, address, and I/O pins that permit independent, asynchronous access for reads or writes to any location in memory. To assist in arbitrating between ports, a fully independent semaphore logic block is provided. This block contains unassigned flags which can be accessed by either side; however, only one side can control the flag at any time. An automatic power down feature, controlled by $\overline{\text{CE}}$ and $\overline{\text{SEM}}$, permits the on-chip circuitry of each port to enter a very low standby power mode (both $\overline{\text{CE}}$ and $\overline{\text{SEM}}$ High).

Fabricated using IDT's CMOS high-performance technology, this device typically operates on only 500mW of power. Low-power (LA) versions offer battery backup data retention capability, with each port typically consuming 200 μW from a 2V battery. The device is packaged in either a 64-pin TQFP, thin quad plastic flatpack, or a 52-pin PLCC.

FUNCTIONAL BLOCK DIAGRAM



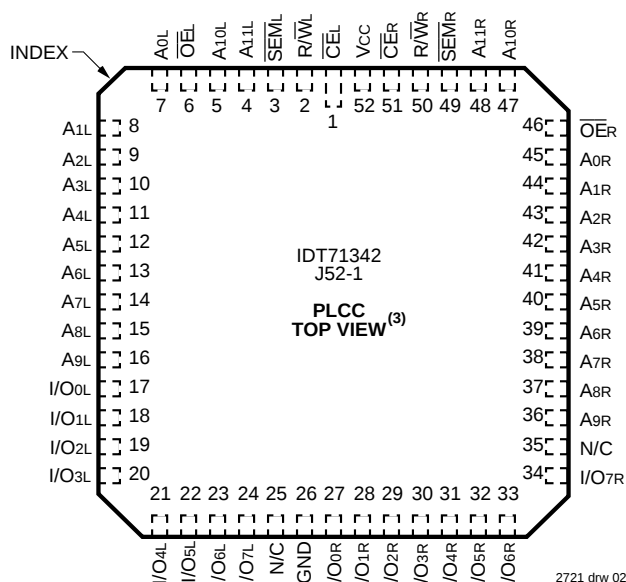
2721 drw 01

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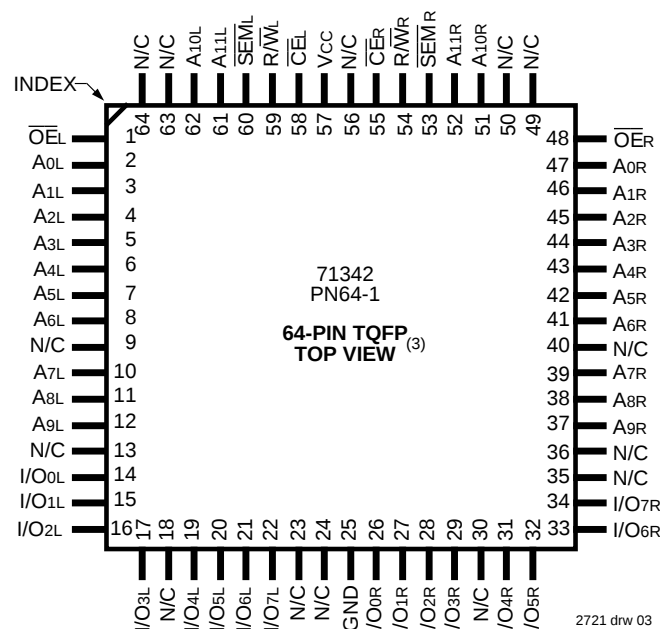
COMMERCIAL TEMPERATURE RANGE

OCTOBER 1996

PIN CONFIGURATIONS^(1,2)



2721 drw 02



2721 drw 03

NOTES:

1. All Vcc pins must be connected to the power supply.
2. All GND pins must be connected to the ground supply.
3. This text does not indicate orientation of the actual part-marking.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Rating	Com'l.	Mil.	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to Ground	-0.5 to +7.0	-0.5 to +7.0	V
TA	Operating Temperature	0 to +70	-55 to +125	°C
TBIAS	Temperature Under Bias	-55 to +125	-65 to +135	°C
TSTG	Storage Temperature	-55 to +125	-65 to +150	°C
PT ⁽³⁾	Power Dissipation	1.5	1.5	W
IOUT	DC Output Current	50	50	mA

NOTES:

2721 tbl 01

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. VTERM must not exceed Vcc + 0.5V for more than 25% of the cycle time or 10 ns maximum, and is limited to ≤ 20mA for the period of VTERM ≥ Vcc + 0.5V.

CAPACITANCE⁽¹⁾

(TA = +25°C, f = 1.0MHz) TQFP Only

Symbol	Parameter	Conditions ⁽²⁾	Max.	Unit
CIN	Input Capacitance	VIN = 3dV	9	pF
COUT	Output Capacitance	VOUT = 3dV	10	pF

NOTES:

2721 tbl 02

1. This parameter is determined by device characterization but is not production tested.
2. 3dV references the interpolated capacitance when the input and output signals switch from 0V to 3V and from 3V to 0V.

RECOMMENDED OPERATING TEMPERATURE AND SUPPLY VOLTAGE

Grade	Ambient Temperature	GND	Vcc
Commercial	0°C to +70°C	0V	5.0V ± 10%

2721 tbl 03

RECOMMENDED DC OPERATING CONDITIONS

Symbol	Parameter	Min.	Typ.	Max.	Unit
Vcc	Supply Voltage	4.5	5.0	5.5	V
GND	Ground	0	0	0	V
VIH	Input High Voltage	2.2	—	6.0 ⁽²⁾	V
VIL	Input Low Voltage	-0.5 ⁽¹⁾	—	0.8	V

NOTES:

2721 tbl 04

1. VIL (min.) ≥ -1.5V for pulse width less than 10ns.
2. VTERM must not exceed Vcc + 0.5V.

DC ELECTRICAL CHARACTERISTICS OVER THE OPERATING TEMPERATURE AND SUPPLY VOLTAGE ($V_{CC} = 5V \pm 10\%$)

Symbol	Parameter	Test Conditions	IDT71342SA		IDT71342LA		Unit
			Min.	Max.	Min.	Max.	
I _{LI}	Input Leakage Current ⁽¹⁾	$V_{CC} = 5.5V$, $V_{IN} = 0V$ to V_{CC}	—	10	—	5	μA
I _{LO}	Output Leakage Current	$\overline{CE} = V_{IH}$, $V_{OUT} = 0V$ to V_{CC}	—	10	—	5	μA
V _{OL}	Output Low Voltage	I _{OL} = 6mA	—	0.4	—	0.4	V
		I _{OL} = 8mA	—	0.5	—	0.5	V
V _{OH}	Output High Voltage	I _{OH} = -4mA	2.4	—	2.4	—	V

NOTE:

1. At $V_{CC} \leq 2.0V$ input leakages are undefined.

2721 tbl 05

DC ELECTRICAL CHARACTERISTICS OVER THE OPERATING TEMPERATURE AND SUPPLY VOLTAGE RANGE⁽¹⁾ ($V_{CC} = 5.0V \pm 10\%$)

Symbol	Parameter	Test Conditions	Version	71342X20		71342X25		71342X35		71342X45		71342X55		71342X70		Unit
				Typ. ⁽²⁾	Max.	Typ. ⁽²⁾	Max.	Typ. ⁽²⁾	Max.	Typ. ⁽²⁾	Max.	Typ. ⁽²⁾	Max.	Typ. ⁽²⁾	Max.	
ICC	Dynamic Operating Current (Both Ports Active)	$\overline{CE} = V_{IL}$ Outputs Open SEM = Don't Care $f = f_{MAX}^{(3)}$	COM'L. S	—	280	—	280	—	260	—	240	—	240	—	240	mA
			L	—	240	—	240	—	220	—	200	—	200	—	200	
ICC1	Dynamic Operating Current (Semaphores Both Sides)	$\overline{CE} = V_{IH}$ Outputs Open SEM $\leq V_{IL}$ $f = f_{MAX}^{(3)}$	COM'L. S	—	280	—	200	—	185	—	170	—	170	—	170	mA
			L	—	240	—	170	—	155	—	140	—	140	—	140	
ISB1	Standby Current (Both Ports—TTL Level Inputs)	$\overline{CE}_L$ and $\overline{CE}_R = V_{IH}$ SEML = SEMR $\geq V_{IH}$ $f = f_{MAX}^{(3)}$	COM'L. S	25	80	25	80	25	75	25	70	25	70	25	70	mA
			L	25	80	25	50	25	45	25	40	25	40	25	40	
ISB2	Standby Current (One Port—TTL Level Inputs)	$\overline{CE}^A = V_{IL}$ and $\overline{CE}^B = V_{IH}^{(5)}$ Active Port Outputs Open, $f = f_{MAX}^{(3)}$	COM'L. S	—	180	—	180	—	170	—	160	—	160	—	160	mA
			L	—	150	—	150	—	140	—	130	—	130	—	130	
ISB3	Full Standby Current (Both Ports—All CMOS Level Inputs)	Both Ports $\overline{CE}_L$ and $\overline{CE}_R \geq V_{CC} - 0.2V$ $V_{IN} \geq V_{CC} - 0.2V$ or $V_{IN} \leq 0.2V$ SEML = SEMR $\geq V_{CC} - 0.2V$, $f = 0^{(4)}$	COM'L. S	1.0	15	1.0	15	1.0	15	1.0	15	1.0	15	1.0	15	mA
			L	0.2	4.5	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	
ISB4	Full Standby Current (One Port—All CMOS Level Inputs)	One Port $\overline{CE}^A$ or $\overline{CE}^B \geq V_{CC} - 0.2V$ $V_{IN} \geq V_{CC} - 0.2V$ or $V_{IN} \leq 0.2V$ SEML = SEMR $\geq V_{CC} - 0.2V$ Active Port Outputs Open, $f = f_{MAX}^{(3)}$	COM'L. S	—	170	—	170	—	150	—	150	—	150	—	150	mA
			L	—	140	—	140	—	130	—	120	—	120	—	120	

NOTES:

- "X" in part number indicates power rating (SA or LA).
- $V_{CC} = 5V$, $T_A = +25^\circ C$ for typical values, and parameters are not production tested.
- $f_{MAX} = 1/t_{RC} =$ All inputs cycling at $f = 1/t_{RC}$ (except Output Enable).
- $f = 0$ means no address or control lines change. Applies only to inputs at CMOS level standby ISB3.
- Port "A" may be either left or right port. Port "B" is opposite from port "A".

2721 tbl 06

DATA RETENTION CHARACTERISTICS

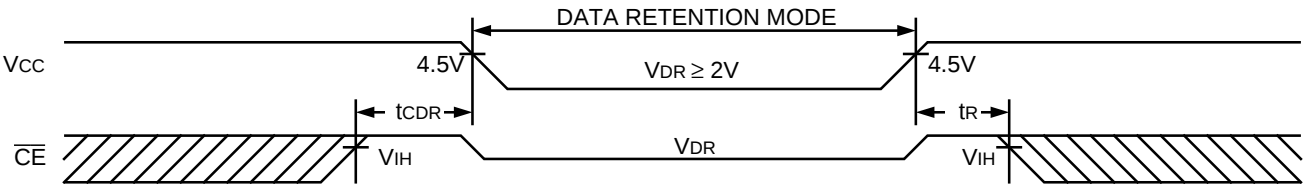
(LA Version Only) $V_{LC} = 0.2V$, $V_{HC} = V_{CC} - 0.2V$

Symbol	Parameter	Test Condition	Min.	Typ. ⁽¹⁾	Max.	Unit
VDR	VCC for Data Retention	—	2.0	—	—	V
IccDR	Data Retention Current	$V_{CC} = 2V$, $\overline{CE} \geq V_{HC}$ COM'L. $\overline{SEM} \geq V_{HC}$	—	100	1500	μA
tCDR ⁽³⁾	Chip Deselect to Data Retention Time	$V_{IN} \geq V_{HC}$ or $\leq V_{LC}$	0	—	—	ns
tR ⁽³⁾	Operation Recovery Time		tRC ⁽²⁾	—	—	ns

2721 tbl 07

- NOTES:**
- $V_{CC} = 2V$, $T_A = +25^{\circ}C$, and are not production tested.
 - tRC = Read Cycle Time.
 - This parameter is guaranteed by device characterization, but is not production tested.

DATA RETENTION WAVEFORM

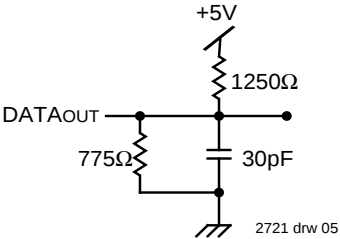


2721 drw 04

AC TEST CONDITIONS

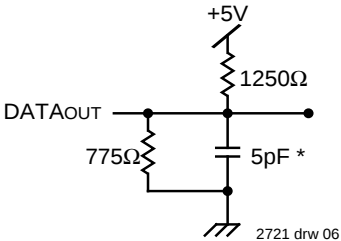
Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	5ns
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
Output Load	Figures 1 and 2

2721 tbl 08



2721 drw 05

Figure 1. AC Output Test Load



2721 drw 06

Figure 2. Output Test Load
(for tLZ, tHZ, twz, tow)
*Including scope and jig

AC ELECTRICAL CHARACTERISTICS OVER THE OPERATING TEMPERATURE AND SUPPLY VOLTAGE⁽⁴⁾

Symbol	Parameter	71342X20		71342X25		71342X35		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
READ CYCLE								
tRC	Read Cycle Time	20	—	25	—	35	—	ns
tAA	Address Access Time	—	20	—	25	—	35	ns
tACE	Chip Enable Access Time ⁽³⁾	—	20	—	25	—	35	ns
tAOE	Output Enable Access Time	—	15	—	15	—	20	ns
tOH	Output Hold from Address Change	0	—	0	—	0	—	ns
tLZ	Output Low-Z Time ^(1, 2)	0	—	0	—	0	—	ns
tHZ	Output High-Z Time ^(1, 2)	—	15	—	15	—	20	ns
tPU	Chip Enable to Power Up Time ⁽²⁾	0	—	0	—	0	—	ns
tPD	Chip Disable to Power Down Time ⁽²⁾	—	50	—	50	—	50	ns
tSOP	SEM Flag Update Pulse ($\overline{OE}$ or $\overline{SEM}$)	—	—	10	—	15	—	ns
twDD	Write Pulse to Data Delay ⁽⁴⁾	—	40	—	50	—	60	ns
tDDD	Write Data Valid to Read Data Delay ⁽⁴⁾	—	30	—	30	—	35	ns
tsAA	Semaphore Address Access Time	—	—	—	25	—	35	ns

2721 tbl 09

AC ELECTRICAL CHARACTERISTICS OVER THE OPERATING TEMPERATURE AND SUPPLY VOLTAGE⁽⁴⁾ (CONT'D)

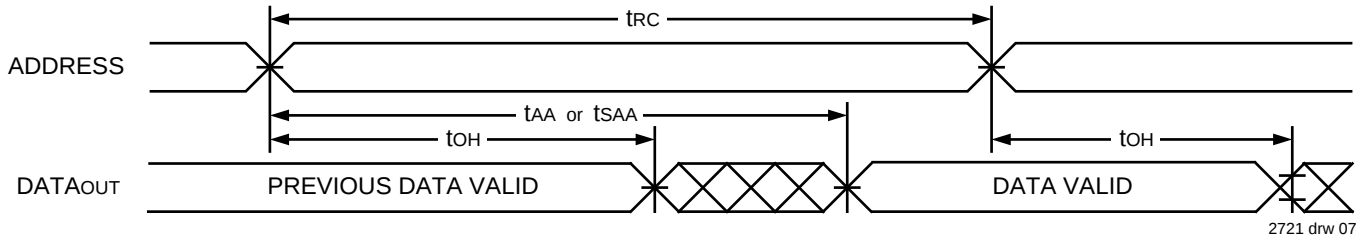
Symbol	Parameter	71342X45		71342X55		71342X70		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
READ CYCLE								
tRC	Read Cycle Time	45	—	55	—	70	—	ns
tAA	Address Access Time	—	45	—	55	—	70	ns
tACE	Chip Enable Access Time ⁽³⁾	—	45	—	55	—	70	ns
tAOE	Output Enable Access Time	—	25	—	30	—	40	ns
tOH	Output Hold from Address Change	0	—	0	—	0	—	ns
tLZ	Output Low-Z Time ^(1, 2)	5	—	5	—	5	—	ns
tHZ	Output High-Z Time ^(1, 2)	—	20	—	25	—	30	ns
tPU	Chip Enable to Power Up Time ⁽²⁾	0	—	0	—	0	—	ns
tpD	Chip Disable to Power Down Time ⁽²⁾	—	50	—	50	—	50	ns
tSOP	SEM Flag Update Pulse ($\overline{OE}$ or $\overline{SEM}$)	15	—	20	—	20	—	ns
twDD	Write Pulse to Data Delay ⁽⁴⁾	—	70	—	80	—	90	ns
tDDD	Write Data Valid to Read Data Delay ⁽⁴⁾	—	45	—	55	—	70	ns
tSAA	Semaphore Address Access Time	—	45	—	55	—	70	ns

NOTES:

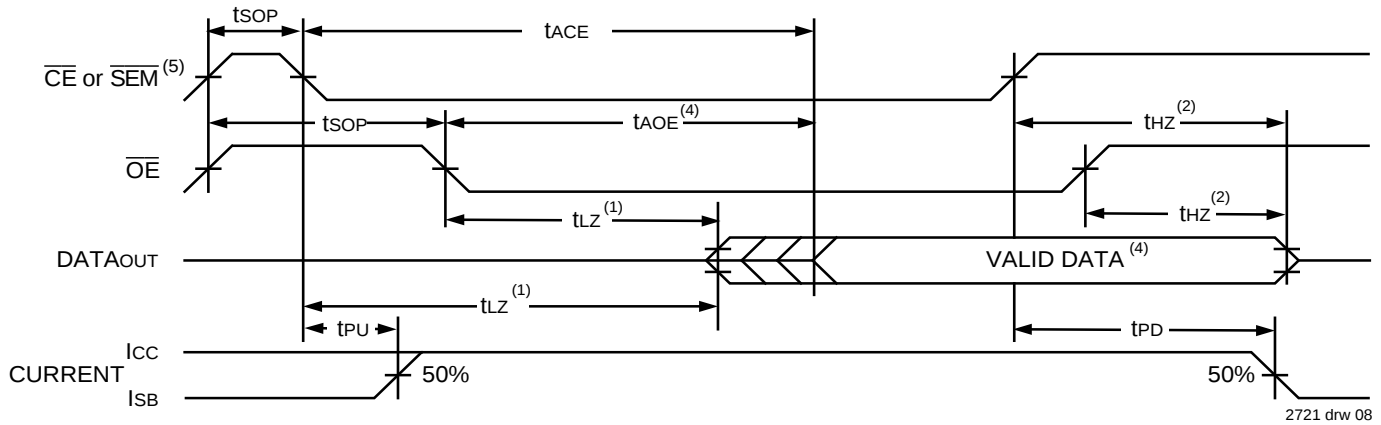
1. Transition is measured $\pm 500\text{mV}$ from Low or High-impedance voltage with the Output Test Load (Figure 2).
2. This parameter is guaranteed by device characterization, but is not production tested.
3. To access RAM, $\overline{CE} = V_{IL}$, $\overline{SEM} = V_{IH}$. To access semaphore, $\overline{CE} = V_{IH}$, and $\overline{SEM} = V_{IL}$.
4. "X" in part number indicates power rating (SA or LA).

2721 tbl 10

TIMING WAVEFORM OF READ CYCLE NO. 1, EITHER SIDE^(1, 2, 4, 6)



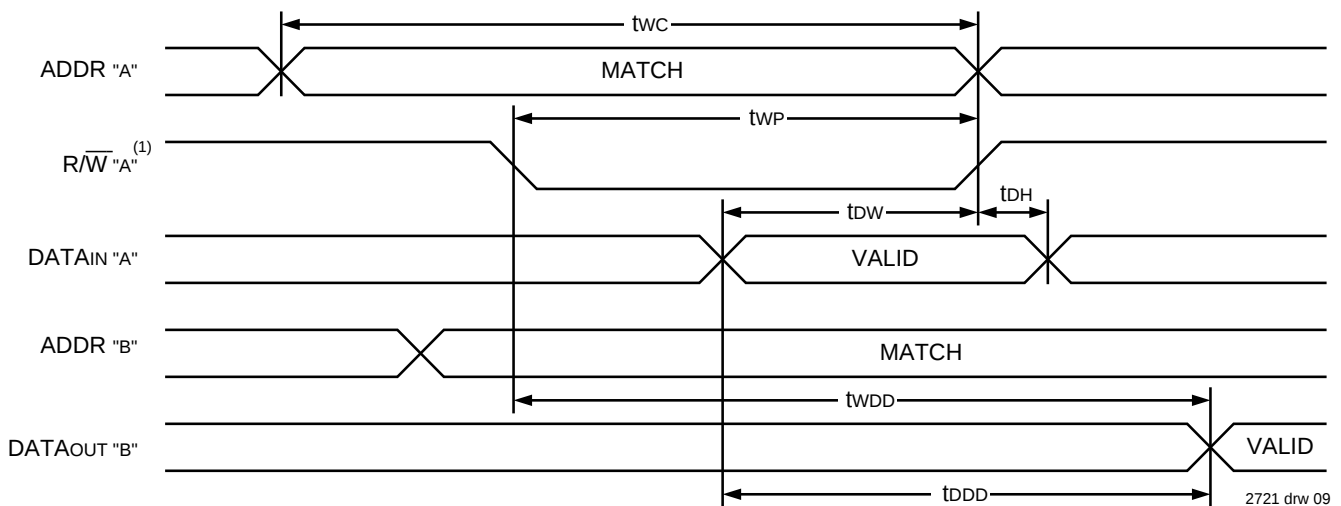
TIMING WAVEFORM OF READ CYCLE NO. 2, EITHER SIDE^(1, 3)



NOTES:

1. Timing depends on which signal is asserted last, $\overline{OE}$ or $\overline{CE}$.
2. Timing depends on which signal is de-asserted first, $\overline{OE}$ or $\overline{CE}$.
3. $R/\overline{W} = V_{IH}$ and address is valid prior to or coincident with $\overline{CE}$ transition Low.
4. Start of valid data depends on which timing becomes effective last; t_{AOE} , t_{ACE} , or t_{AA} .
5. To access RAM, $\overline{CE} = V_{IL}$ and $\overline{SEM} = V_{IH}$. To access semaphore, $\overline{CE} = V_{IH}$ and $\overline{SEM} = V_{IL}$. t_{AA} is for RAM Address Access and t_{SAA} is for Semaphore Address Access.
6. $R/\overline{W} = V_{IH}$, $\overline{CE} = V_{IL}$, and $\overline{OE} = V_{IL}$. Address is valid prior to or coincident with $\overline{CE}$ transition Low.

TIMING WAVEFORM OF WRITE WITH PORT-TO-PORT READ^(1, 2)



NOTES:

1. Write cycle parameters should be adhered to, in order to ensure proper writing.
2. $\overline{CE}_L = \overline{CE}_R = V_{IL}$. $\overline{CE}_B = V_{IL}$.
3. Port "A" may be either left or right port. Port "B" is the opposite from port "A".

AC ELECTRICAL CHARACTERISTICS OVER THE OPERATING TEMPERATURE AND SUPPLY VOLTAGE⁽⁵⁾

Symbol	Parameter	71342X20		71342X25		71342X35		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
WRITE CYCLE								
tWC	Write Cycle Time	20	—	25	—	35	—	ns
tEW	Chip Enable to End-of-Write ⁽³⁾	15	—	20	—	30	—	ns
tAW	Address Valid to End-of-Write	15	—	20	—	30	—	ns
tAS	Address Set-up Time	0	—	0	—	0	—	ns
tWP	Write Pulse Width	15	—	20	—	25	—	ns
tWR	Write Recovery Time	0	—	0	—	0	—	ns
tDW	Data Valid to End-of-Write	15	—	15	—	20	—	ns
tHZ	Output High-Z Time ^(1, 2)	—	15	—	15	—	20	ns
tDH	Data Hold Time ⁽⁴⁾	0	—	0	—	3	—	ns
twZ	Write Enabled to Output in High-Z ^(1, 2)	—	15	—	15	—	20	ns
tOW	Output Active from End-of-Write ^(1, 2, 4)	3	—	3	—	3	—	ns
tSWR	SEM Flag Write to Read Time	10	—	10	—	10	—	ns
tSPS	SEM Flag Contention Window	10	—	10	—	10	—	ns

2721 tbl 11

AC ELECTRICAL CHARACTERISTICS OVER THE OPERATING TEMPERATURE AND SUPPLY VOLTAGE⁽⁵⁾(CONT'D)

Symbol	Parameter	71342X45		71342X55		71342X70		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
WRITE CYCLE								
tWC	Write Cycle Time	45	—	55	—	70	—	ns
tEW	Chip Enable to End-of-Write ⁽³⁾	40	—	50	—	60	—	ns
tAW	Address Valid to End-of-Write	40	—	50	—	60	—	ns
tAS	Address Set-up Time	0	—	0	—	0	—	ns
tWP	Write Pulse Width	40	—	50	—	60	—	ns
tWR	Write Recovery Time	0	—	0	—	0	—	ns
tDW	Data Valid to End-of-Write	20	—	25	—	30	—	ns
tHZ	Output High-Z Time ^(1, 2)	—	20	—	25	—	30	ns
tDH	Data Hold Time ⁽⁴⁾	3	—	3	—	3	—	ns
twZ	Write Enabled to Output in High-Z ^(1, 2)	—	20	—	25	—	30	ns
tOW	Output Active from End-of-Write ^(1, 2, 4)	3	—	3	—	3	—	ns
tSWR	SEM Flag Write to Read Time	10	—	10	—	10	—	ns
tSPS	SEM Flag Contention Window	10	—	10	—	10	—	ns

2721 tbl 12

NOTES:

1. Transition is measured $\pm 500\text{mV}$ from Low or High-impedance voltage with Output Test Load (Figure 2).
2. This parameter is guaranteed by device characterization but is not production tested.
3. To access RAM, $\overline{\text{CE}} = \text{V}_{\text{IL}}$ and $\overline{\text{SEM}} = \text{V}_{\text{IH}}$. To access semaphore, $\overline{\text{CE}} = \text{V}_{\text{IH}}$ and $\overline{\text{SEM}} = \text{V}_{\text{IL}}$. Either condition must be valid for the entire tEW time.
4. The specification for tDH must be met by the device supplying write data to the RAM under all operating conditions. Although tDH and tow values will vary over voltage and temperature, the actual tDH will always be smaller than the actual tow.
5. "X" in part number indicates power rating (SA or LA).

[illegible]

2721 drw 10

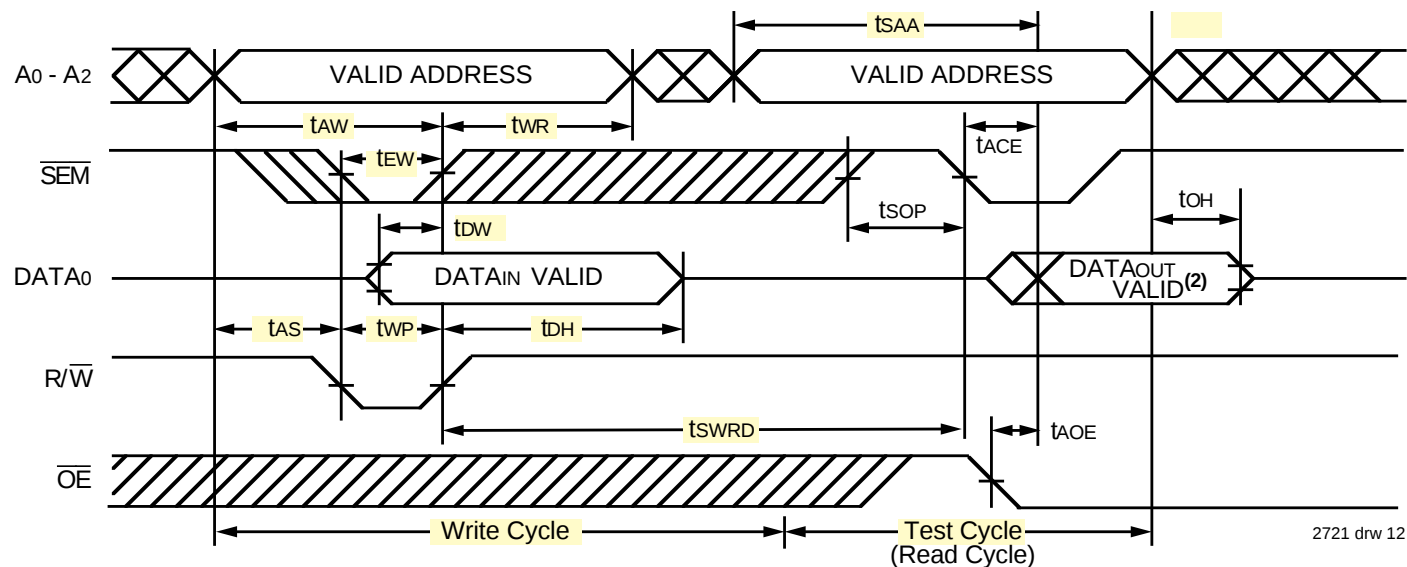
The timing diagram illustrates the relationship between the ADDRESS, $\overline{\text{CE}}$ or $\overline{\text{SEM}}$, $\overline{\text{R/W}}$, and DATAIN signals. The signals are shown as digital waveforms over time. The timing parameters are defined as follows:

- t_{WC} : Width of the ADDRESS signal pulse.
- t_{AW} : Address-to-Write delay, from the falling edge of ADDRESS to the start of DATAIN.
- $t_{\text{AS}}^{(6)}$: Address-to-Setup delay, from the falling edge of ADDRESS to the start of DATAIN.
- $t_{\text{EW}}^{(2)}$: Enable-to-Write delay, from the falling edge of $\overline{\text{CE}}$ or $\overline{\text{SEM}}$ to the start of DATAIN.
- $t_{\text{WR}}^{(3)}$: Write-to-Restore delay, from the rising edge of $\overline{\text{CE}}$ or $\overline{\text{SEM}}$ to the end of DATAIN.
- t_{DW} : Data-to-Write delay, from the falling edge of ADDRESS to the start of DATAIN.
- t_{DH} : Data-to-Hold delay, from the rising edge of ADDRESS to the end of DATAIN.

2721 drw 11

1. $\overline{R/\overline{W}}$ or $\overline{CE}$ must be High during all address transitions.
2. A write occurs during the overlap (t_{EW} or t_{WP}) of either $\overline{CE}$ or $\overline{SEM} = V_{IL}$ and $\overline{R/\overline{W}} = V_{IL}$.
3. t_{WR} is measured from the earlier of $\overline{CE}$ or $\overline{R/\overline{W}}$ going High to the end-of-write cycle.
4. During this period, the I/O pins are in the output state, and input signals must not be applied.
5. If the $\overline{CE}$ Low transition occurs simultaneously with or after the $\overline{R/\overline{W}}$ Low transition, the outputs remain in the High-impedance state.
6. Timing depends on which enable signal ($\overline{CE}$ or $\overline{R/\overline{W}}$) is asserted last.
7. This parameter is guaranteed by device characterization, but is not production tested. Transition is measured $\pm 500\text{mV}$ from steady state with the Output Test Load (Figure 2).
8. If $\overline{OE}$ is Low during a $\overline{R/\overline{W}}$ controlled write cycle, the write pulse width must be the larger of t_{WP} or ($t_{WZ} + t_{OW}$) to allow the I/O drivers to turn off data to be placed on the bus for the required t_{OW} . If $\overline{OE}$ is High during an $\overline{R/\overline{W}}$ controlled write cycle, this requirement does not apply and the write pulse can be as short as the specified t_{WP} .
9. To access RAM, $\overline{CE} = V_{IL}$ and $\overline{SEM} = V_{IH}$. To access semaphore, $\overline{CE} = V_{IH}$ and $\overline{SEM} = V_{IL}$. Either condition must be valid for the entire t_{EW} time.

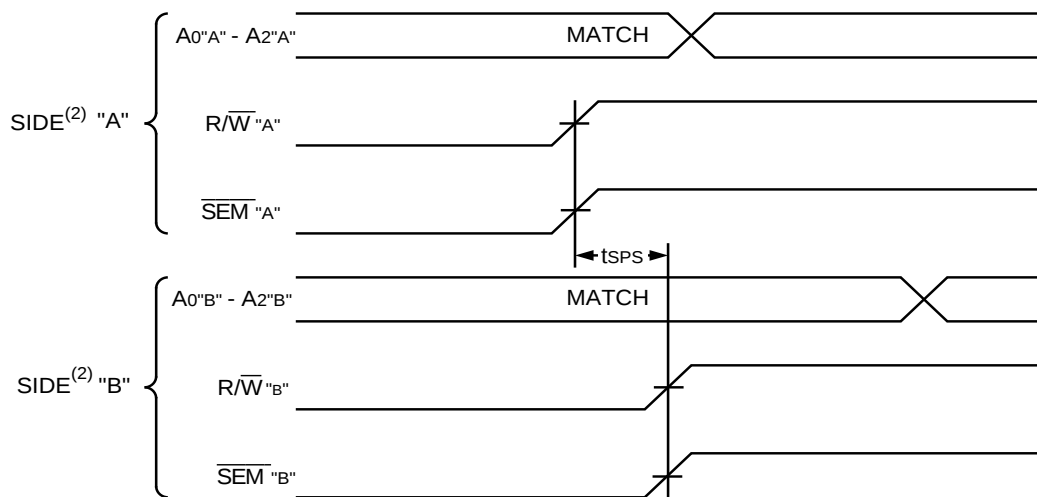
TIMING WAVEFORM OF SEMAPHORE READ AFTER WRITE TIMING, EITHER SIDE⁽¹⁾



NOTES:

1. $\overline{CE} = V_{IH}$ for the duration of the above timing (both write and read cycle).
2. "DATAout VALID" represents all I/O's (I/O₀-I/O₇) equal to the semaphore value.

TIMING WAVEFORM OF SEMAPHORE CONTENTION^(1, 3, 4)



NOTES:

1. $D_{0R} = D_{0L} = V_{IL}$, $\overline{CE}_R = \overline{CE}_L = V_{IH}$, Semaphore Flag is released from both sides (reads as ones from both sides) at cycle start.
2. All timing is the same for left and right ports. Port "A" may be either left or right port. Port "B" is the opposite from port "A".
3. This parameter is measured from the point where R/W "A" or SEM "A" goes High until R/W "B" or SEM "B" goes High.
4. If tSPS is not satisfied, there is no guarantee which side will be granted the semaphore flag.

FUNCTIONAL DESCRIPTION

The IDT71342 is an extremely fast Dual-Port 4K x 8 CMOS Static RAM with an additional 8 address locations dedicated to binary semaphore flags. These flags allow either processor on the left or right side of the Dual-Port RAM to claim a privilege over the other processor for functions defined by the system designer's software. As an example, the semaphore can be used by one processor to inhibit the other from accessing a portion of the Dual-Port RAM or any other shared resource.

The Dual-Port RAM features a fast access time, and both ports are completely independent of each other. This means that the activity on the left port in no way slows the access time of the right port. Both ports are identical in function to standard CMOS Static RAMs and can be read from or written to at the same time, with the only possible conflict arising from the simultaneous writing of, or a simultaneous READ/WRITE of, a non-semaphore location. Semaphores are protected against such ambiguous situations and may be used by the system program to avoid any conflicts in the non-semaphore portion of the Dual-Port RAM. These devices have an automatic power-down feature controlled by $\overline{CE}$, the Dual-Port RAM enable, and $\overline{SEM}$, the semaphore enable. The $\overline{CE}$ and $\overline{SEM}$ pins control on-chip power down circuitry that permits the respective port to go into standby mode when not selected. This is the condition which is shown in Table 1 where $\overline{CE}$ and $\overline{SEM}$ are both high.

Systems which can best use the IDT71342 contain multiple processors or controllers and are typically very high-speed systems which are software controlled or software intensive. These systems can benefit from a performance increase offered by the IDT71342's hardware semaphores, which provide a lockout mechanism without requiring complex programming.

Software handshaking between processors offers the maximum in system flexibility by permitting shared resources to be allocated in varying configurations. The IDT71342 does not use its semaphore flags to control any resources through hardware, thus allowing the system designer total flexibility in system architecture.

An advantage of using semaphores rather than the more common methods of hardware arbitration is that wait states are never incurred in either processor. This can prove to be a major advantage in very high-speed systems.

HOW THE SEMAPHORE FLAGS WORK

The semaphore logic is a set of eight latches which are independent of the Dual-Port RAM. These latches can be used to pass a flag, or token, from one port to the other to indicate that a shared resource is in use. The semaphores provide a hardware assist for a use assignment method called "Token Passing Allocation." In this method, the state of a semaphore latch is used as a token indicating that a shared resource is in use. If the left processor wants to use this resource, it requests the token by setting the latch. This processor then verifies its success in setting the latch by

reading it. If it was successful, it proceeds to assume control over the shared resource. If it was not successful in setting the latch, it determines that the right side processor had set the latch first, has the token and is using the shared resource. The left processor can then either repeatedly request that semaphore's status or remove its request for that semaphore to perform another task and occasionally attempt again to gain control of the token via the set and test sequence. Once the right side has relinquished the token, the left side should succeed in gaining control.

The semaphore flags are active low. A token is requested by writing a zero into a semaphore latch and is released when the same side writes a one to that latch.

The eight semaphore flags reside within the IDT71342 in a separate memory space from the Dual-Port RAM. This address space is accessed by placing a low input on the $\overline{SEM}$ pin (which acts as a chip select for the semaphore flags) and using the other control pins (Address, $\overline{OE}$, and $R/\overline{W}$) as they would be used in accessing a standard Static RAM. Each of the flags has a unique address which can be accessed by either side through the address pins A₀–A₂. When accessing the semaphores, none of the other address pins has any effect.

When writing to a semaphore, only data pin D₀ is used. If a low level is written into an unused semaphore location, that flag will be set to a zero on that side and a one on the other (see Table II). That semaphore can now only be modified by the side showing the zero. When a one is written into the same location from the same side, the flag will be set to a one for both sides (unless a semaphore request from the other side is pending) and then can be written to by both sides. The fact that the side which is able to write a zero into a semaphore subsequently locks out writes from the other side is what makes semaphore flags useful in interprocessor communications. (A thorough discussion on the use of this feature follows shortly.) A zero written into the same location from the other side will be stored in the semaphore request latch for that side until the semaphore is freed by the first side.

When a semaphore flag is read, its value is spread into all data bits so that a flag that is a one reads as a one in all data bits and a flag containing a zero reads as all zeros. The read value is latched into one side's output register when that side's semaphore select ($\overline{SEM}$) and output enable ($\overline{OE}$) signals go active. This serves to disallow the semaphore from changing state in the middle of a read cycle due to a write cycle from the other side. Because of this latch, a repeated read of a semaphore in a test loop must cause either signal ($\overline{SEM}$ or $\overline{OE}$) to go inactive or the output will never change.

A sequence of WRITE/READ must be used by the semaphore in order to guarantee that no system level contention will occur. A processor requests access to shared resources by attempting to write a zero into a semaphore location. If the semaphore is already in use, the semaphore request latch will contain a zero, yet the semaphore flag will appear as a one, a fact which the processor will verify by the subsequent read (see Table II). As an example, assume a

processor writes a zero in the left port at a free semaphore location. On a subsequent read, the processor will verify that it has written successfully to that location and will assume control over the resource in question. Meanwhile, if a processor on the right side attempts to write a zero to the same semaphore flag it will fail, as will be verified by the fact that a one will be read from that semaphore on the right side during a subsequent read. Had a sequence of READ/WRITE been used instead, system contention problems could have occurred during the gap between the read and write cycles.

It is important to note that a failed semaphore request must be followed by either repeated reads or by writing a one into the same location. The reason for this is easily understood by looking at the simple logic diagram of the semaphore flag in Figure 3. Two semaphore request latches feed into a semaphore flag. Whichever latch is first to present a zero to

the semaphore flag will force its side of the semaphore flag low and the other side high. This condition will continue until a one is written to the same semaphore request latch. Should the other side's semaphore request latch have been written to a zero in the meantime, the semaphore flag will now stay low until its semaphore request latch is written to a one. From this it is easy to understand that, if a semaphore is requested and the processor which requested it no longer needs the resource, the entire can hang up until a one is written into that semaphore request latch.

The critical case of semaphore timing is when both sides request a single token by attempting to write a zero into it at the same time. The semaphore logic is specially designed to resolve this problem. If simultaneous requests are made, the logic guarantees that only one side receives the token. If one side is earlier than the other in making the request, the first

TABLE I — NON-CONTENTION READ/WRITE CONTROL

Left or Right Port ⁽¹⁾					Function
R/W	CE	SEM	OE	D0-7	
X	H	H	X	Z	Port Disabled and in Power Down Mode
H	H	L	L	DATAOUT	Data in Semaphore Flag Output on Port
X	X	X	H	Z	Output Disabled
↗	H	L	X	DATAIN	Port Data Bit D0 Written Into Semaphore Flag
H	L	H	L	DATAOUT	Data in Memory Output on Port
L	L	H	X	DATAIN	Data on Port Written Into Memory
X	L	L	X	—	Not Allowed

2721 tbl 13

NOTE:

1. AOL = A10L ≠ A0R - A10R.

"H" = HIGH, "L" = LOW, "X" = Don't Care, "Z" = High-impedance, and "↗" = Low-to-High transition.

TABLE II — EXAMPLE SEMAPHORE PROCUREMENT SEQUENCE^(1,2)

Function	D0 - D7 Left	D0 - D7 Right	Status
No Action	1	1	Semaphore free
Left Port Writes "0" to Semaphore	0	1	Left port has semaphore token
Right Port Writes "0" to Semaphore	0	1	No change. Right side has no write access to semaphore
Left Port Writes "1" to Semaphore	1	0	Right port obtains semaphore token
Left Port Writes "0" to Semaphore	1	0	No change. Left side has no write access to semaphore
Right Port Writes "1" to Semaphore	0	1	Left port obtains semaphore token
Left Port Writes "1" to Semaphore	1	1	Semaphore free
Right Port Writes "0" to Semaphore	1	0	Right port has semaphore token
Right Port Writes "1" to Semaphore	1	1	Semaphore free
Left Port Writes "0" to Semaphore	0	1	Left port has semaphore token
Left Port Writes "1" to Semaphore	1	1	Semaphore free

2721 tbl 14

NOTES:

1. This table denotes a sequence of events for only one of the eight semaphores on the IDT71342.

2. There are eight semaphore flags written to via I/O₀ and read from all I/O's (I/O₀-I/O₇). These eight semaphores are addressed by A₀ - A₂.

side to make the request will receive the token. If both requests arrive at the same time, the assignment will be arbitrarily made to one port or the other.

One caution that should be noted when using semaphores is that semaphores alone do not guarantee that access to a resource is secure. As with any powerful programming technique, if semaphores are misused or misinterpreted, a software error can easily happen. Code integrity is of the utmost importance when semaphores are used instead of slower, more restrictive hardware intensive schemes.

Initialization of the semaphores is not automatic and must be handled via the initialization program at power up. Since any semaphore request flag which contains a zero must be reset to a one, all semaphores on both sides should have a one written into them at initialization from both sides to assure that they will be free when needed.

USING SEMAPHORES—Some examples

Perhaps the simplest application of semaphores is their application as resource markers for the IDT71342's Dual-Port RAM. Say the 4K x 8 RAM was to be divided into two 2K x 8 blocks which were to be dedicated at any one time to servicing either the left or right port. Semaphore 0 could be used to indicate the side which would control the lower section of memory, and Semaphore 1 could be defined as the indicator for the upper section of the memory.

To take a resource, in this example the lower 2K of Dual-Port RAM, the processor on the left port could write and then read a zero into Semaphore 0. If this task were successfully completed (a zero was read back rather than a one), the left processor would assume control of the lower 2K. Meanwhile, the right processor would attempt to perform the same function. Since this processor was attempting to gain control of the resource after the left processor, it would read back a one in response to the zero it had attempted to write into Semaphore 0. At this point, the software could choose to try and gain control of the second 2K section by writing, then reading a zero into Semaphore 1. If it succeeded in gaining control, it would lock out the left side.

Once the left side was finished with its task, it would write

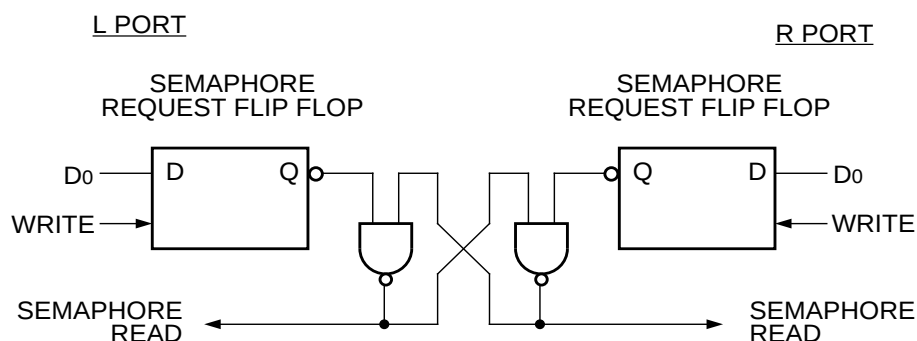
a one to Semaphore 0 and may then try to gain access to Semaphore 1. If Semaphore 1 was still occupied by the right side, the left side could undo its semaphore request and perform other tasks until it was able to write, then read a zero into Semaphore 1. If the right processor performs a similar task with Semaphore 0, this protocol would allow the two processors to swap 2K blocks of Dual-Port RAM with each other.

The blocks do not have to be by any particular size and can even be variable, depending upon the complexity of the software using the semaphore flags. All eight semaphores could be used to divide the Dual-Port RAM or other shared resources into eight parts. Semaphores can even be assigned different meanings on different sides rather than being given a common meaning as was shown in the example above.

Semaphores are a useful form of arbitration in systems like disk interfaces where the CPU must be locked out of a section of memory during a transfer and the I/O device cannot tolerate any wait states. With the use of semaphores, once the two devices had determined which memory area was "off limits" to the CPU, both the CPU and the I/O devices could access their assigned portions of memory continuously without any wait states.

Semaphores are also useful in applications where no memory "WAIT" state is available on one or both sides. Once a semaphore handshake has been performed, both processors can access their assigned RAM segments at full speed.

Another application is in the area of complex data structures. In this case, block arbitration is very important. For this application one processor may be responsible for building and updating a data structure. The other processor then reads and interprets that data structure. If the interpreting processor reads an incomplete data structure, a major error condition may exist. Therefore, some sort of arbitration must be used between the two different processors. The building processor arbitrates for the block, locks it and then is able to go in and update the data structure. When the update is completed, the data structure block is released. This allows the interpreting processor to come back and read the complete data structure, thereby guaranteeing a consistent data structure.



2721 drw 14

Figure 3. IDT71342 Semaphore Logic

ORDERING INFORMATION

IDT	XXXX Device Type	A Power	999 Speed	A Package	A Process/ Temperature Range		
						Blank	Commercial (0°C to +70°C)
						J PF	52-pin PLCC (J52-1) 64-pin TQFP (PN64-1)
						20 25 35 45 55 70	} Speed in nanoseconds
						LA SA	Low Power Standard Power
						71342	32K (4K x 8-Bit) Dual-Port RAM w/ Semaphore

2721 drw 15